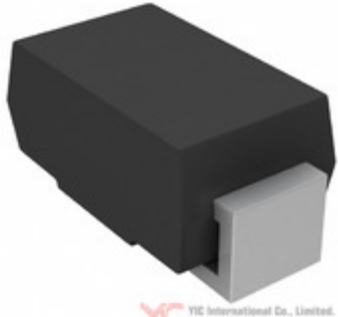
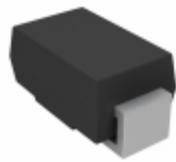
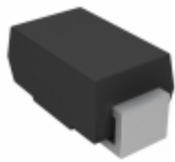


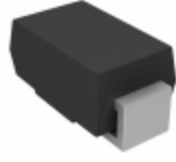
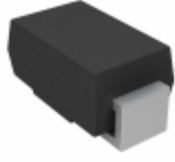
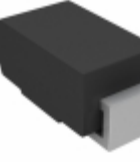
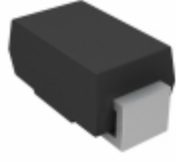
	<h2>S1GHE3_A/H</h2>
	<p>Hersteller-Teilenummer: S1GHE3_A/H</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: DIODE GEN PURP 400V 1A DO214AC</p> <p>Datenblätter: 1.S1GHE3_A/H.pdf 2.S1GHE3_A/H.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3689 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1GHE3_A/H
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	DIODE GEN PURP 400V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	3689 pcs Stock
detaillierte Beschreibung	Diode Standard 400V 1A Surface Mount DO-214AC
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 400V
Spannung - Sperr (Vr) (max)	400V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)
Basisteilenummer	S1G
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	S1GHE3_A/H-ND

S1GHE3_A/H ist neu im Original, Suche S1GHE3_A/H Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1GHE3_A/H Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage S1GHE3_A/H: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S1GHE3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p>S1GHE3_A/I Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p>S1GHM2G TSC (Taiwan Semiconductor) DIODE GEN PURP 400V 1A DO214AC</p>	 <p>S1GHM3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>
 <p>S1GHE3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p>S1GHE3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p>S1GHE3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p>S1GHE3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>

heiße Teile

Mehr

04025U0R2BAT2A	24AA024T-I/SNG	CSNE151-204	D FQL40N50F	FTSH-107-01-L-DH-C-TR
GF1M-E3/5CA	HAF1009-91STL-E	LM2587T-ADJ	NTC-L107K10TRD	P0901AA2
P6SMB550CA	RM250AH-5H	S1G-003/5AT	S1G-003HE3/5AT	S1G-008/11
D S1G-012/5A	S1G-012/5AT	S1G-13-93-F	S1G-13-F	S1G-13-F-89
S1G-13-G-89	S1G-61HE3J/61T	S1G-6428E3/11	S1G-6601	S1G-6904E3/61
S1G-6904E3/61T	S1G-6904LF/11T	D S1G-E3/5AT	S1G-E3/5AT	S1G-E3/61T
S1G-E3/61T	D S1G-GS/61T	S1G-M3/61T	S1G-M3/61T	S1G-TR13
S1GA-E3/61T	S1GA-E3/61T	S1GB-13-F	S1GHE3/5AT	S1GHE3/5AT
S1GHE3/61T	S1GHE3/61T	S1GHE3_A/H	D S1GT-04LC-F	S1G_R1_10001
SD107WS-7-F	SI2323DS-T1-GE3	SI8902EDB-T2	SK18TR-13	SN74HC165APWR

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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